

## ESDALC6V1xxM6

### 4 and 5 line low capacitance TRANSIL™ array for ESD protection

### **Main applications**

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems
- Cellular phone handsets and accessories
- Video equipment

#### **Features**

- 4 unidirectional TRANSIL diodes (ESDALC6V1M6)
- 5 unidirectional TRANSIL diodes (ESDALC6V1-5M6)
- Breakdown Voltage V<sub>BR</sub> = 6.1 V min
- Low diode capacitance (12 pF typ at 0 V)
- Low leakage current < 70 nA</p>
- Very small PCB area: 1.45 mm²
- 500 microns pitch
- Leadfree package

#### **Description**

The ESDALC6V1xxM6 is monolithic arrays designed to protect up to 4 or 5 lines against ESD transients.

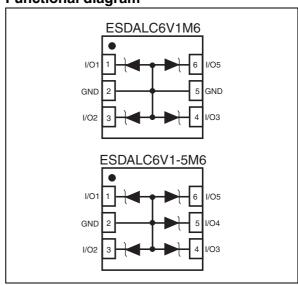
The device is ideal for applications where both reduced print circuit board space and power absorption capability are required.

#### **Benefits**

- High ESD protection level
- High integration
- Suitable for high density boards



#### **Functional diagram**



#### **Order Code**

Part number	Marking
ESDALC6V1M6	G
ESDALC6V1-5M6	Н

#### Complies with the following standards:

#### IEC61000-4-2

15 kV (air discharge) 8 kV (contact discharge) MIL STD 883E- Method 3015-7: class3 25 kV (human body model)

TM: TRANSIL is a trademark of STMicroelectronics

Characteristics ESDALC6V1xxM6

## 1 Characteristics

Table 1. Absolute maximum ratings ( $T_{amb} = 25$  °C)

Symbol	Parameter			Unit
V <sub>PP</sub>	ESD discharge – IEC61000-4-2 air discharge IEC61000-4-2 contact discharge		± 15 ± 8	kV
P <sub>PP</sub>	Peak pulse power dissipation (8/20 $\mu$ s) <sup>(1)</sup> $T_j$ initial = $T_{amb}$		30	W
I <sub>pp</sub>	Repetitive peak pulse current typical value (8/20	3	Α	
Tj	Junction temperature	125	Ô	
T <sub>stg</sub>	Storage temperature range	-55 + 150	°C	
T <sub>L</sub>	Maximum lead temperature for soldering during 1	260	Ô	
T <sub>OP</sub>	Operating temperature range	-40 + 125	°C	

<sup>1.</sup> For a surge greater than the maximum values, the diode will fail in short-circuit.

Table 2. Electrical characteristics ( $T_{amb} = 25$  °C)

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Symbol	Parameter	14
V <sub>RM</sub>	Stand-off voltage	1 <sub>F</sub>
V <sub>BR</sub>	Breakdown voltage	
V <sub>CL</sub>	Clamping voltage	V <sub>CL</sub> V <sub>BR</sub> V <sub>RM</sub>
I <sub>RM</sub>	Leakage current @ V <sub>RM</sub>	I <sub>RM</sub>
I <sub>PP</sub>	Peak pulse current	
αΤ	Voltage temperature coefficient	Slope= 1/R <sub>d</sub>
V <sub>F</sub>	Forward voltage drop	

Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>BR</sub>	I <sub>R</sub> = 1 mA			7.2	V
I <sub>RM</sub>	V <sub>RM</sub> = 3 V			70	nA
V <sub>F</sub>	I <sub>F</sub> = 10 mA			1	V
R <sub>d</sub>			2	3	Ω
αT <sup>(1)</sup>	$I_R = 1 \text{ mA},$			5	10 <sup>-4</sup> /°C
С	$V_R = 0 \text{ V DC}, F = 1 \text{ MHz}, V_{OSC} = 30 \text{ mV}_{RMS}$		12	15	pF

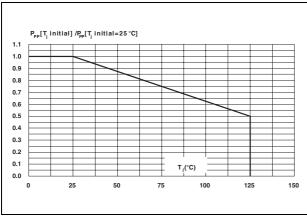
<sup>1.</sup>  $\Delta V_{BR} = \alpha T * (T_{amb} - 25 °C) * V_{BR} (25 °C)$ 

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ESDALC6V1xxM6 Characteristics

Figure 1. Relative variation of peak pulse power versus initial junction temperature

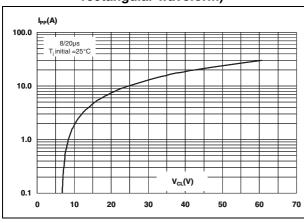
Figure 2. Peak pulse power versus exponential pulse duration



P<sub>PP</sub>(W)
1000
1000
1000
1000
1000
1000

Figure 3. Clamping voltage versus peak pulse current (typical values, rectangular waveform)

Figure 4. Forward voltage drop versus peak forward current (typical values)



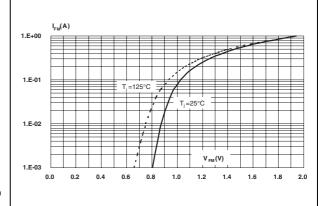
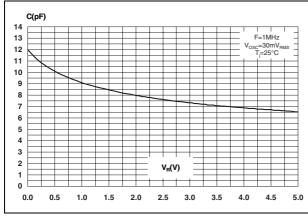
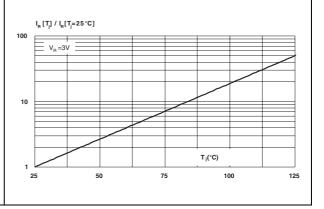


Figure 5. Junction capacitance vesus reverse voltage applied (typical values)

Figure 6. Relative variation of leakage current versus junction temperature (typical values)





Characteristics ESDALC6V1xxM6

Figure 7. S21 attenuation measurement results of each channel

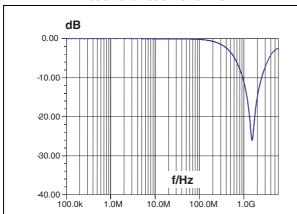


Figure 8. Analog crosstalk measurements between channels

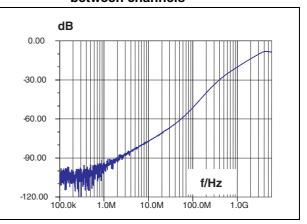
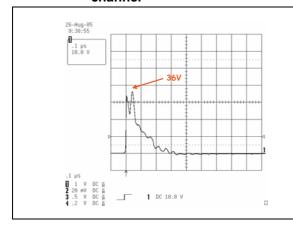
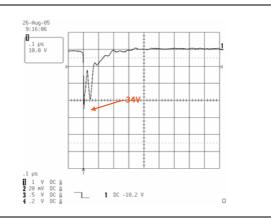


Figure 9. ESD response to IEC6100-4-2 (+15 kV air discharge) on each channel

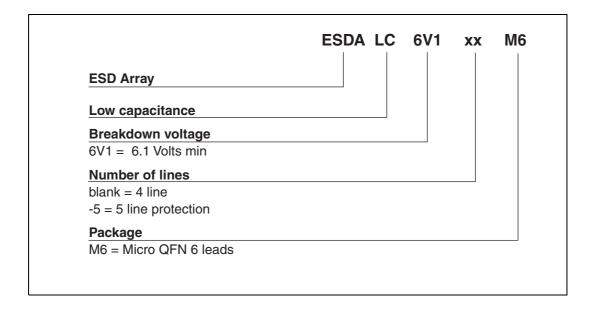
Figure 10. ESD response to IEC6100-4-2 (-15 kV air discharge) on each channel





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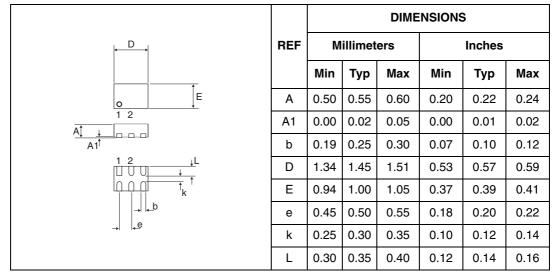
## 2 Ordering information scheme



## 3 Package information

Epoxy meets UL94, V0

Table 3. Mechanical data



Package information ESDALC6V1xxM6

Figure 11. Footprint

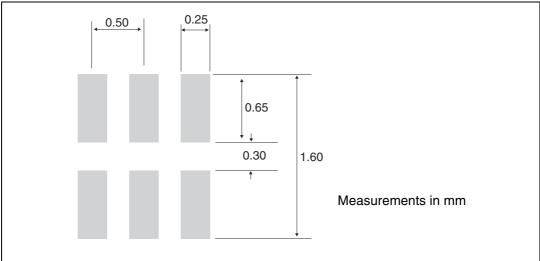
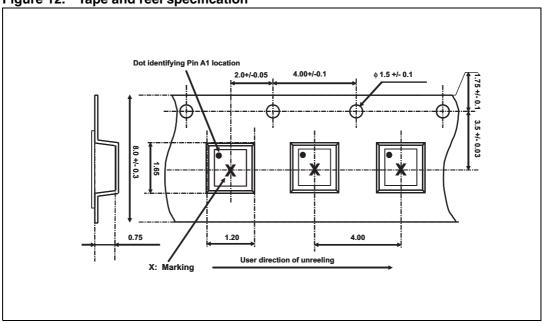


Figure 12. Tape and reel specification



Note:

Product marking may be rotated by 90° for assembly plant differentiation. In no case should this product marking be used to orient the component for its placement on a PCB. Only pin 1 mark is to be used for this purpose.

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

# 4 Ordering information

Part number	Marking	Package	Weight	Base qty	Delivery mode
ESDALC6V1M6	G	Micro QFN	2.2 mg	30,000	Tape and reel
ESDALC6V1-5M6	Н	Micro QFN	2.2 mg	30,000	Tape and reel

# 5 Revision history

Date	Revision	Changes	
19-Sep-2005	1	Initial release.	
10-Oct-2005	2	Package title changed from DFN to QFN. No technical changes.	
21-Dec-2005	3	Updated package dimensions in Table 1.	
01-Fev-2007	01-Fev-2007  4 Reformatted to current standard. Added note on marking rotation in section 3. Package information		

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